

MITSUBISHI TRANSISTOR MODULES  
**QM30E2Y/E3Y-H**

MEDIUM POWER SWITCHING USE  
 INSULATED TYPE

**QM30E2Y/E3Y-H**



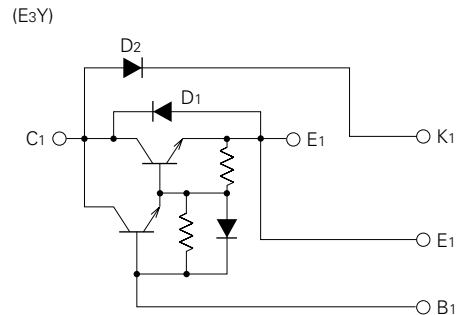
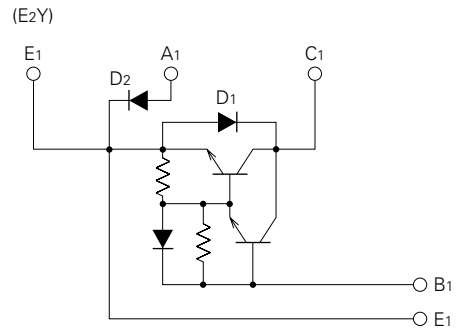
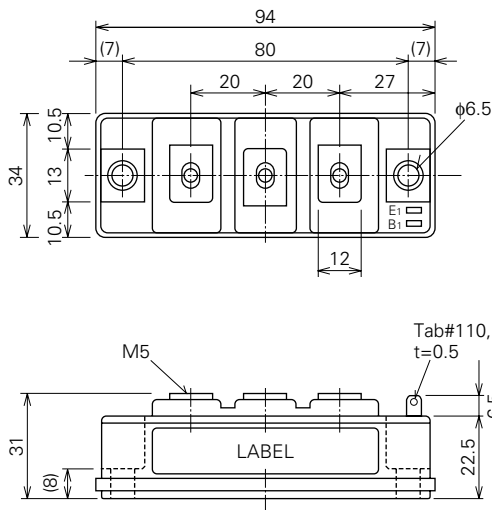
- **I<sub>c</sub>** Collector current ..... **30A**
- **V<sub>CEX</sub>** Collector-emitter voltage ..... **600V**
- **h<sub>FE</sub>** DC current gain ..... **75**
- **Insulated Type**
- **UL Recognized**  
 Yellow Card No. E80276 (N)  
 File No. E80271

**APPLICATION**

DC chopper, DC motor controllers, Inverters

**OUTLINE DRAWING & CIRCUIT DIAGRAM**

Dimensions in mm



Feb.1999



## QM30E2Y/E3Y-H

MEDIUM POWER SWITCHING USE  
INSULATED TYPE**ABSOLUTE MAXIMUM RATINGS** (Transistor part including D1,  $T_j=25^\circ\text{C}$ )

| Symbol                 | Parameter                                               | Conditions                                  | Ratings | Unit |
|------------------------|---------------------------------------------------------|---------------------------------------------|---------|------|
| V <sub>CEX</sub> (SUS) | Collector-emitter voltage                               | I <sub>c</sub> =1A, V <sub>EB</sub> =2V     | 600     | V    |
| V <sub>CEX</sub>       | Collector-emitter voltage                               | V <sub>EB</sub> =2V                         | 600     | V    |
| V <sub>CBO</sub>       | Collector-base voltage                                  | Emitter open                                | 600     | V    |
| V <sub>EBO</sub>       | Emitter-base voltage                                    | Collector open                              | 7       | V    |
| I <sub>c</sub>         | Collector current                                       | DC                                          | 30      | A    |
| -I <sub>c</sub>        | Collector reverse current                               | DC (forward diode current)                  | 30      | A    |
| P <sub>c</sub>         | Collector dissipation                                   | T <sub>c</sub> =25°C                        | 250     | W    |
| I <sub>B</sub>         | Base current                                            | DC                                          | 1.8     | A    |
| -I <sub>CSM</sub>      | Surge collector reverse current (forward diode current) | Peak value of one cycle of 60Hz (half wave) | 300     | A    |

**ABSOLUTE MAXIMUM RATINGS** (Diode part (D2),  $T_j=25^\circ\text{C}$ )

| Symbol                      | Parameter                              | Conditions                                  | Ratings               | Unit             |
|-----------------------------|----------------------------------------|---------------------------------------------|-----------------------|------------------|
| V <sub>RRM</sub>            | Repetitive peak reverse voltage        |                                             | 600                   | V                |
| V <sub>RRSM</sub>           | Non-repetitive peak reverse voltage    |                                             | 720                   | V                |
| V <sub>R</sub> (DC)         | DC reverse voltage                     |                                             | 480                   | V                |
| I <sub>DC</sub>             | DC current                             | DC circuit, resistive, inductive load       | 30                    | A                |
| I <sub>FSM</sub>            | Surge (non-repetitive) forward current | Peak value of one cycle of 60Hz (half wave) | 600                   | A                |
| I <sub>t</sub> <sup>2</sup> | I <sub>t</sub> <sup>2</sup> for fusing | Value for one cycle of surge current        | 1.5 × 10 <sup>3</sup> | A <sup>2</sup> s |

**ABSOLUTE MAXIMUM RATINGS** (Common)

| Symbol           | Parameter            | Conditions                            | Ratings   | Unit  |
|------------------|----------------------|---------------------------------------|-----------|-------|
| T <sub>j</sub>   | Junction temperature |                                       | -40~150   | °C    |
| T <sub>stg</sub> | Storage temperature  |                                       | -40~125   | °C    |
| V <sub>iso</sub> | Isolation voltage    | Charged part to case, AC for 1 minute | 2500      | V     |
| —                | Mounting torque      | Main terminal screw M5                | 1.47~1.96 | N·m   |
|                  |                      |                                       | 15~20     | kg·cm |
|                  |                      | Mounting screw M6                     | 1.96~2.94 | N·m   |
|                  |                      |                                       | 20~30     | kg·cm |
| —                | Weight               | Typical value                         | 210       | g     |

**ELECTRICAL CHARACTERISTICS** (Transistor part including D1,  $T_j=25^\circ\text{C}$ )

| Symbol                  | Parameter                                | Test conditions                                                                     | Limits |      |      | Unit |
|-------------------------|------------------------------------------|-------------------------------------------------------------------------------------|--------|------|------|------|
|                         |                                          |                                                                                     | Min.   | Typ. | Max. |      |
| I <sub>CEX</sub>        | Collector cutoff current                 | V <sub>CE</sub> =600V, V <sub>EB</sub> =2V                                          | —      | —    | 1.0  | mA   |
| I <sub>CBO</sub>        | Collector cutoff current                 | V <sub>CB</sub> =600V, Emitter open                                                 | —      | —    | 1.0  | mA   |
| I <sub>EBO</sub>        | Emitter cutoff current                   | V <sub>EB</sub> =7V                                                                 | —      | —    | 200  | mA   |
| V <sub>CE</sub> (sat)   | Collector-emitter saturation voltage     | I <sub>c</sub> =30A, I <sub>B</sub> =0.4A                                           | —      | —    | 2.0  | V    |
| V <sub>BE</sub> (sat)   | Base-emitter saturation voltage          |                                                                                     | —      | —    | 2.5  | V    |
| -V <sub>CEO</sub>       | Collector-emitter reverse voltage        | -I <sub>c</sub> =30A (diode forward voltage)                                        | —      | —    | 1.85 | V    |
| h <sub>FE</sub>         | DC current gain                          | I <sub>c</sub> =30A, V <sub>CE</sub> =2V/5V                                         | 75/100 | —    | —    | —    |
| t <sub>on</sub>         | Switching time                           | V <sub>CC</sub> =300V, I <sub>c</sub> =30A, I <sub>B1</sub> =-I <sub>B2</sub> =0.6A | —      | —    | 1.5  | μs   |
| t <sub>s</sub>          |                                          |                                                                                     | —      | —    | 12   | μs   |
| t <sub>f</sub>          |                                          |                                                                                     | —      | —    | 3.0  | μs   |
| R <sub>th</sub> (j-c) Q | Thermal resistance (junction to case)    | Transistor part                                                                     | —      | —    | 0.5  | °C/W |
| R <sub>th</sub> (j-c) R |                                          | Diode part                                                                          | —      | —    | 2.0  | °C/W |
| R <sub>th</sub> (c-f)   | Contact thermal resistance (case to fin) | Conductive grease applied                                                           | —      | —    | 0.15 | °C/W |

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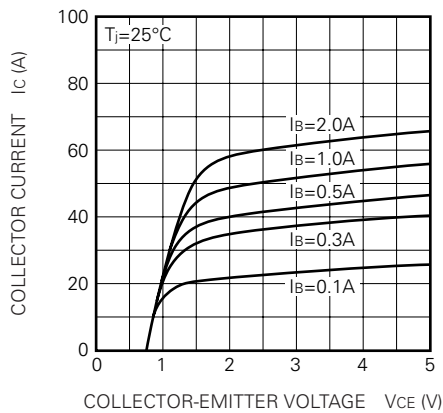
MEDIUM POWER SWITCHING USE  
INSULATED TYPE

## ELECTRICAL CHARACTERISTICS (Diode part (D2), $T_j=25^\circ\text{C}$ )

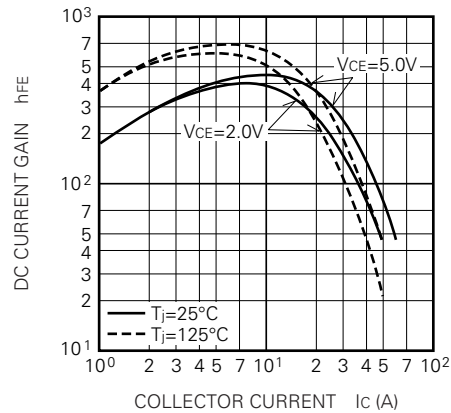
| Symbol        | Parameter                       | Test conditions                                                                         | Limits |      |      | Unit                      |
|---------------|---------------------------------|-----------------------------------------------------------------------------------------|--------|------|------|---------------------------|
|               |                                 |                                                                                         | Min.   | Typ. | Max. |                           |
| $I_{RRM}$     | Repetitive peak reverse current | $V_R=V_{RRM}, T_j=150^\circ\text{C}$                                                    | —      | —    | 5.0  | mA                        |
| $V_{FM}$      | Forward voltage                 | $I_F=30\text{A}$                                                                        | —      | —    | 1.5  | V                         |
| $t_{rr}$      | Reverse recovery time           | $I_F=30\text{A}, di/dt=-60\text{A}/\mu\text{s}, V_R=600\text{V}, T_j=150^\circ\text{C}$ | —      | —    | 0.9  | $\mu\text{s}$             |
| $Q_{rr}$      | Reverse recovery charge         |                                                                                         | —      | —    | 15   | $\mu\text{C}$             |
| $R_{th(j-c)}$ | Thermal resistance              | Junction to case                                                                        | —      | —    | 1.3  | $^\circ\text{C}/\text{W}$ |
| $R_{th(c-f)}$ | Contact thermal resistance      | Conductive grease applied (case to fin)                                                 | —      | —    | 0.15 | $^\circ\text{C}/\text{W}$ |

## PERFORMANCE CURVES

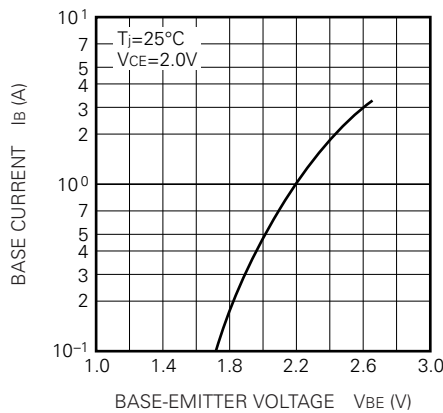
COMMON EMITTER OUTPUT CHARACTERISTICS (TYPICAL)



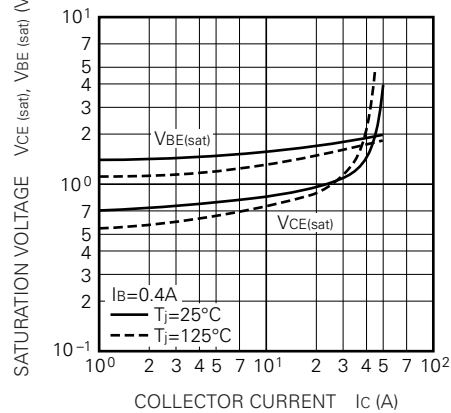
DC CURRENT GAIN VS. COLLECTOR CURRENT (TYPICAL)



COMMON EMITTER INPUT CHARACTERISTIC (TYPICAL)



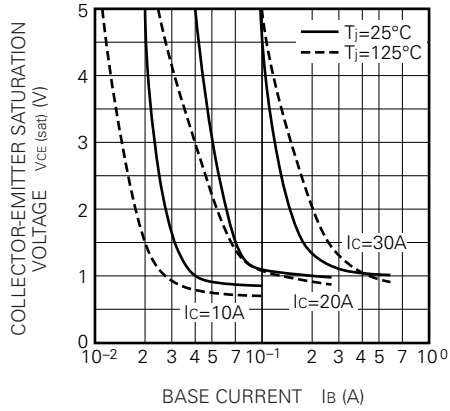
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



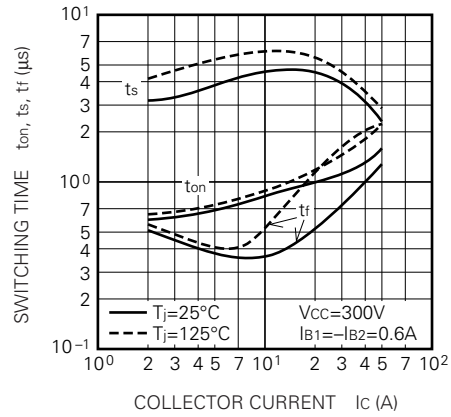
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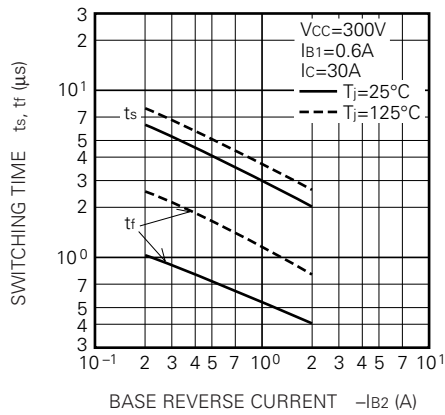
**COLLECTOR-EMITTER SATURATION VOLTAGE (TYPICAL)**



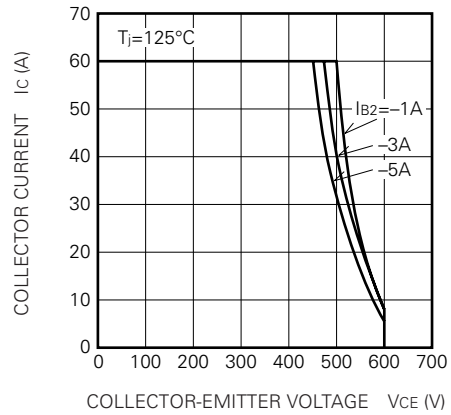
**SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)**



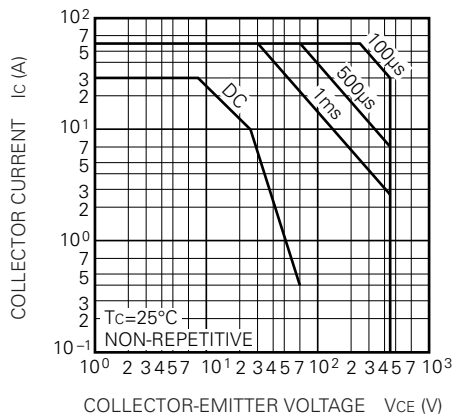
**SWITCHING TIME VS. BASE CURRENT (TYPICAL)**



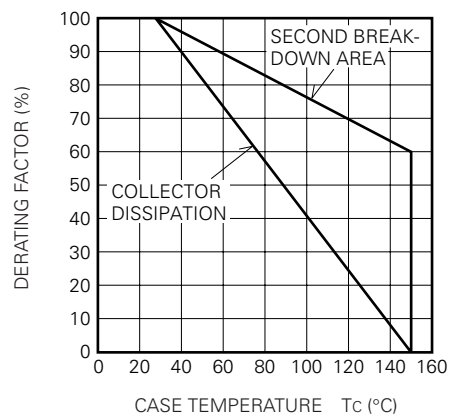
**REVERSE BIAS SAFE OPERATING AREA**



**FORWARD BIAS SAFE OPERATING AREA**

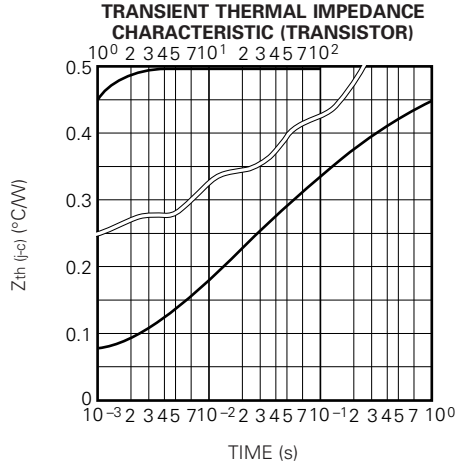


**DERATING FACTOR OF F. B. S. O. A.**

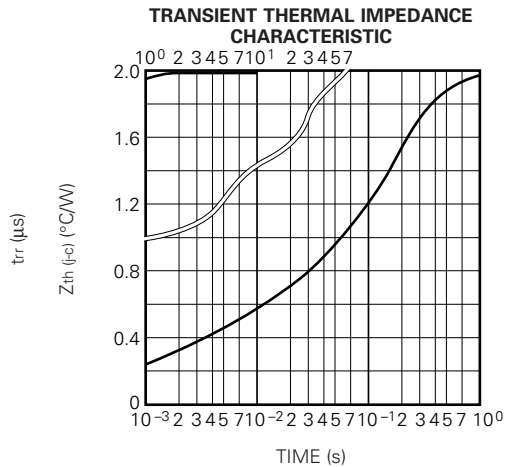
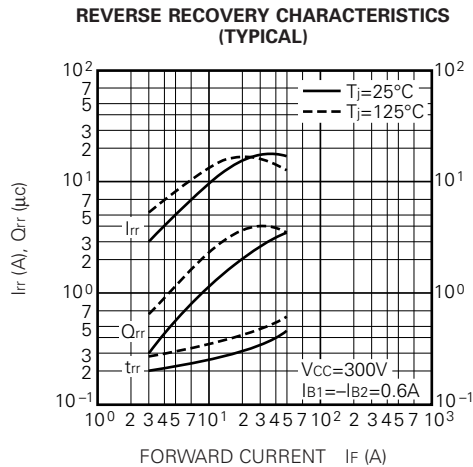
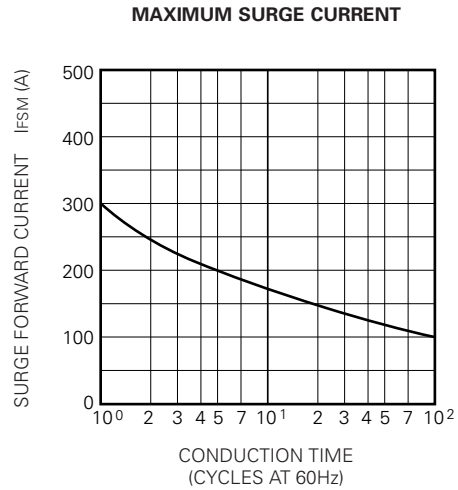
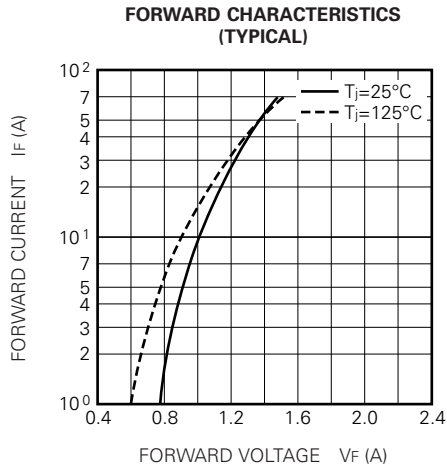


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## PERFORMANCE CURVES (Diode part (D1))

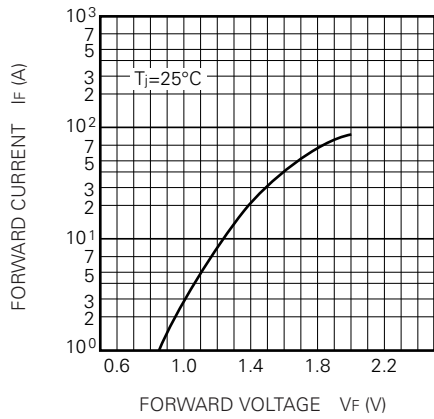


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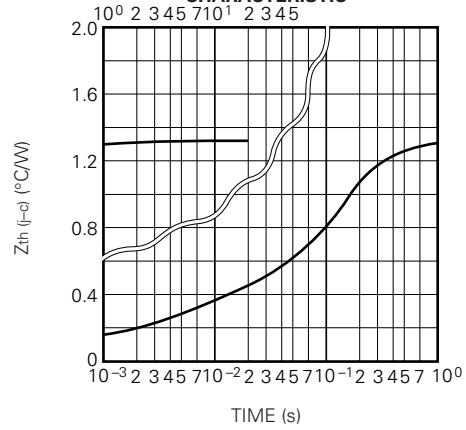
MEDIUM POWER SWITCHING USE  
INSULATED TYPE

## PERFORMANCE CURVES (Diode part (D2))

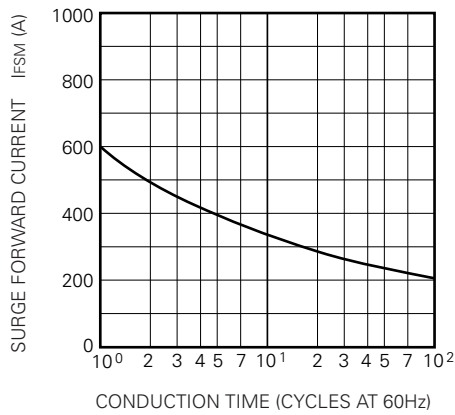
MAXIMUM FORWARD CHARACTERISTIC



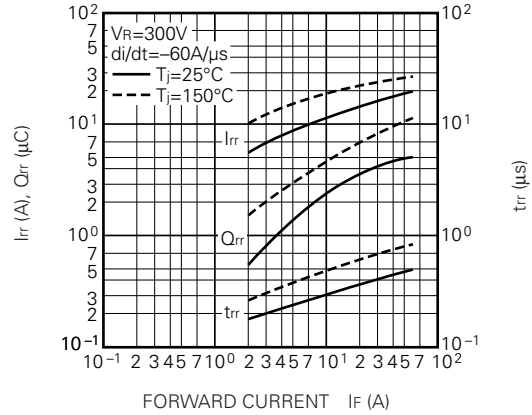
TRANSIENT THERMAL IMPEDANCE CHARACTERISTIC



MAXIMUM SURGE CURRENT



REVERSE RECOVERY CHARACTERISTICS (VS. IF) (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (VS. di/dt) (TYPICAL)

